

SOT23 PNP SILICON PLANAR MEDIUM POWER TRANSISTOR

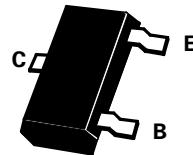
BCW68

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PARTMARKING DETAILS -

BCW68F -	DF	BCW68FR -	7T
BCW68G -	DG	BCW68GR -	5T
BCW68H -	DH	BCW68HR -	7N

COMPLEMENTARY TYPES - BCW66



SOT23

ABSOLUTE MAXIMUM RATINGS.

PARAMETER	SYMBOL	VALUE	UNIT
Collector-Emitter Voltage	V_{CES}	-60	V
Collector-Emitter Voltage	V_{CEO}	-45	V
Emitter-Base Voltage	V_{EBO}	-5	V
Peak Pulse Current(10ms)	I_{CM}	-1000	mA
Continuous Collector Current	I_C	-800	mA
Base Current	I_B	-100	mA
Power Dissipation at $T_{amb}=25^{\circ}C$	P_{tot}	330	mW
Operating and Storage Temperature Range	$T_j; T_{stg}$	-55 to +150	°C

 **ZETEX**

BCW68

ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^\circ C$ unless otherwise stated).

PARAMETER		SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS.
Collector-Emitter Breakdown Voltage		$V_{(BR)CEO}$	-45			V	$I_{CEO}=-10mA$
		$V_{(BR)CES}$	-60				$I_C=-10\mu A$
Emitter-Base Breakdown Voltage		$V_{(BR)EBO}$	-5			V	$I_{EBO}=-10\mu A$
Collector-Emitter Cut-off Current		I_{CES}			-20 -10	nA μA	$V_{CES}=-45V$ $V_{CES}=-45V, T_{amb}=150^\circ C$
Emitter-Base Cut-Off Current		I_{EBO}			-20	nA	$V_{EBO}=-4V$
Collector-Emitter Saturation Voltage		$V_{CE(sat)}$		-0.7	-0.3	V V	$I_C=-100mA, I_B=-10mA$ $I_C=-500mA, I_B=50mA^*$
Base-Emitter Saturation Voltage		$V_{BE(sat)}$			-2	V	$I_C=-500mA, I_B=-50mA^*$
Static Forward Current Transfer	BCW68F	h_{FE}	100 35	170	250		$I_C=-100mA, V_{CE}=-1V^*$ $I_C=500mA, V_{CE}=2V^*$
	BCW68G	h_{FE}	160 60	250	400		$I_C=-100mA, V_{CE}=-1V^*$ $I_C=500mA, V_{CE}=2V^*$
	BCW68H	h_{FE}	250 100	350	630		$I_C=-100mA, V_{CE}=-1V^*$ $I_C=500mA, V_{CE}=2V^*$
Transition Frequency		f_T	100			MHz	$I_C=-20mA, V_{CE}=-10V$ $f=100MHz$
Output Capacitance		C_{obo}		12	18	pF	$V_{CB}=-10V, f=1MHz$
Input Capacitance		C_{ibo}			80	pF	$V_{EB}=-0.5V, f=1MHz$
Noise Figure		N		2	10	dB	$I_C=-0.2mA, V_{CE}=-5V$ $R_G=1K\Omega, f=1KH$ $\Delta f=200Hz$
Switching times: Turn-On Time Turn-Off Time		t_{on} t_{off}			100 400	ns ns	$I_C=-150mA$ $I_{B1}=-I_{B2}=-15mA$ $R_L=150\Omega$

Spice parameter data is available upon request for this device

*Measured under pulsed conditions.

